

STX13004

High voltage fast-switching NPN power transistor

Features

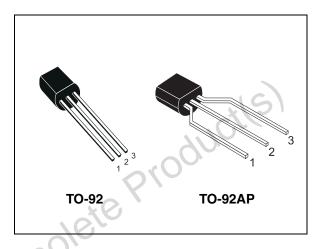
- High voltage capability
- Low spread of dynamic parameters
- Minimum lot-to-lot spread for reliable operation
- Very high switching speed

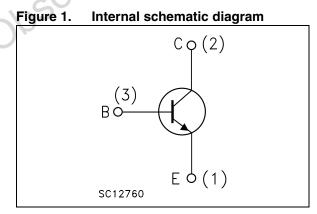
Application

■ SMPS for battery charger

Description

The device is manufactured using high voltage multi epitaxial planar technology for high switching speeds and high voltage capability. It uses a cellular emitter structure with planar edge termination to enhance switching speeds while maintaining the wide RBSOA.





| Order codes | Marking | Package | Packaging |
|--------------------------|---------|---------|-----------|
| STX13004 | X13004 | TO-92 | Bulk |
| STX13004G ⁽¹⁾ | X13004G | TO-92 | Bulk |
| STX13004-AP | X13004 | TO-92AP | Ammopack |
| STX13004G-AP (1) | X13004G | TO-92AP | Ammopack |

1. The letter "G" in the order code identifies the product as ECOPACK®2 grade. Please see Section 3 for details.

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Electrical ratings 1

| Table 2. | Absolute maximum rating | s |
|----------|-------------------------|---|
|----------|-------------------------|---|

| Symbol | Parameter | Value | Unit |
|------------------|---|----------------------|------|
| V _{CES} | Collector-emitter voltage ($V_{BE} = 0$) | 700 | V |
| V _{CEO} | Collector-emitter voltage $(I_B = 0)$ | 400 | V |
| V _{EBO} | Collector-base voltage (I _C = 0, I _B = 1 A, t _P < 10 ms) | V _{(BR)EBO} | V |
| ۱ _C | Collector current | 2 | А |
| I _{CM} | Collector peak current (t _P < 5 ms) | 4 | A |
| Ι _Β | Base current | 1 | A |
| I _{BM} | Base peak current (t _P < 5 ms) | 2 | А |
| P _{TOT} | Total dissipation at $T_c = 25 \text{ °C}$ | 2.5 | W |
| T _{STG} | Storage temperature | -65 to 150 | °C |
| TJ | Max. operating junction temperature | 150 | 0 |

Table 3. Thermal data

| Table 3. Symbol | Thermal data Parameter | Value | Unit |
|--------------------|---|-------|------|
| R _{thJC} | Thermal resistance junction-case max | 50 | °C/W |
| R _{thJA} | Thermal resistance junction-ambient max | 150 | °C/W |
| oleteP | | | |



2 Electrical characteristics

 T_{case} = 25 °C; unless otherwise specified.

| Symbol | Parameter | Test conditions | Min. | Тур. | Max. | Unit |
|--------------------------------------|--|--|----------|------------|------------|----------|
| I _{CES} | Collector cut-off current $(V_{BE} = 0)$ | V _{CE} = 700 V | | | 10 | μA |
| I _{CEO} | Collector cut-off current $(I_B = 0)$ | V _{CE} = 400 V | | | 1 | mA |
| V _{(BR)EBO} | Emitter-base breakdown voltage (I _C = 0) | I _E = 10 mA | 9 | Ċ | 18 | v |
| V _{CEO(sus)} ⁽¹⁾ | Collector-emitter sustaining voltage (I _B = 0) | I _C = 10 mA | 400 | 20 | | V |
| V _{CE(sat)} ⁽¹⁾ | Collector-emitter saturation voltage | $I_{C} = 1 A$ $I_{B} = 200 mA$ $I_{C} = 2 A$ $I_{B} = 500 mA$ | | | 0.5 1 | V V |
| V _{BE(sat)} ⁽¹⁾ | Base-emitter saturation voltage | $I_C = 1 A$ $I_C = 2 A$ $I_B = 200 mA$ $I_B = 500 mA$ | | | 1.2 1.6 | V V |
| h _{FE} | DC current gain | | 26 10 | 35 | 30 16 | |
| t _s t _f | Resistive load Storage time Fall time | $\begin{split} I_{C} &= 2 \ A & t_{p} = 30 \ \mu s \\ I_{B(on)} &= -I_{B(off)} = 400 \ mA \\ V_{CC} &= 125 \ V & V_{BB(off)} = -5 \ V \\ (see \ Figure \ 12) \end{split}$ | | 1.1 300 | | µs ns |
| t _s | Inductive load Storage time Fall time | $ I_C = 1 A \qquad V_{clamp} = 300 V \\ I_{B(on)} = 250 \text{ mA} \qquad V_{BB(off)} = -5 V \\ C_{snubber} = 1 \text{ nF} \qquad R_{BB(off)} = 0 \\ (see Figure 13) $ | | 2.4 200 | | µs ns |

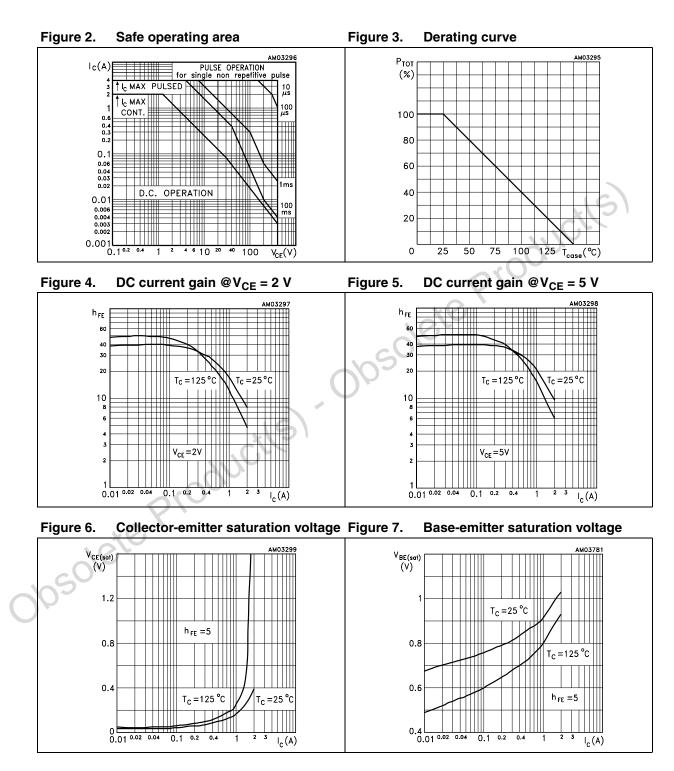
 Table 4.
 Electrical characteristics

1. Pulse test: pulse duration \leq 300 $\mu s,$ duty cycle \leq 2 %.



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2.1 Electrical characteristics (curves)



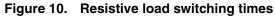
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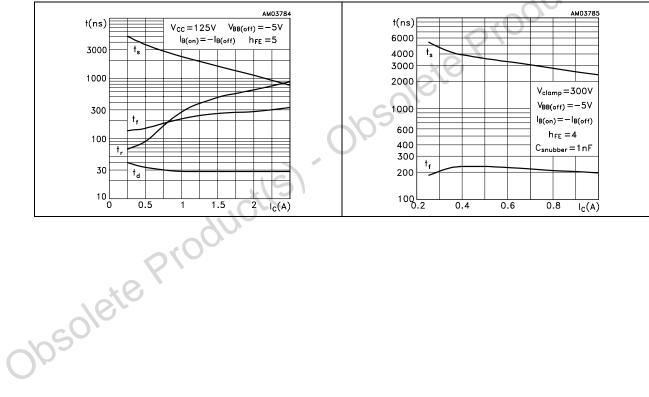


Inductive load switching times

Figure 9. Figure 8. **Output characteristics Reverse biased SOA** AM03783 AM03782 $|_{c}(A)$ $I_{c}(A)$ 180mA I_B=200mA 160mA 4 140mA 1.5 120mA 100mA 3 60mA 40mA 2 l_B=20mA $h_{FE} = 5$ 0.5 $V_{BB(off)} = -5V$ $R_{BB(off)}=0$ 1 0 L 0 0 1 2 3 $V_{CE}(V)$ 200 400 600 $V_{CE}(V)$

Figure 11.







2.2 Test circuits

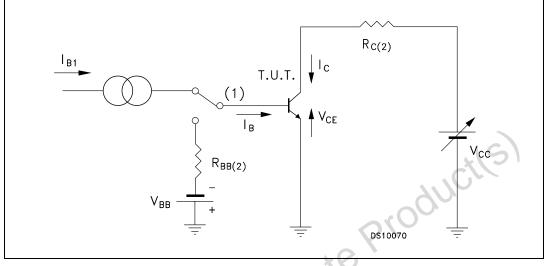
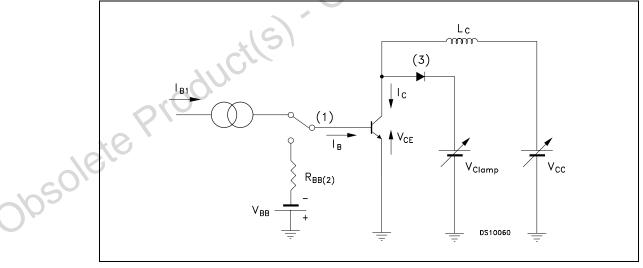


Figure 12. Resistive load switching test circuit

- 1. Fast electronic switch
- 2. Non-inductive resistor





- 1. Fast electronic switch
- 2. Non-inductive resistor
- 3. Fast recovery rectifier



3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK[®] is an ST trademark.

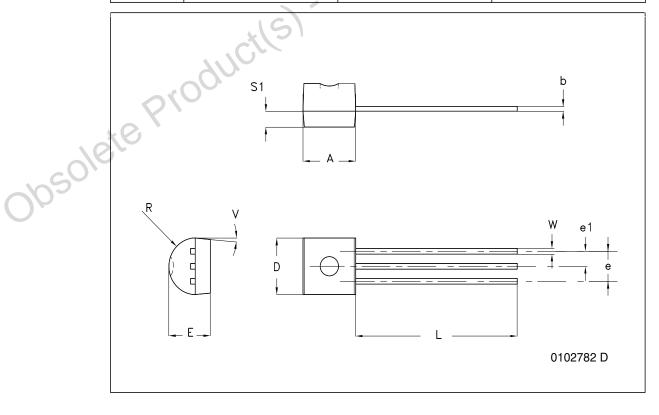
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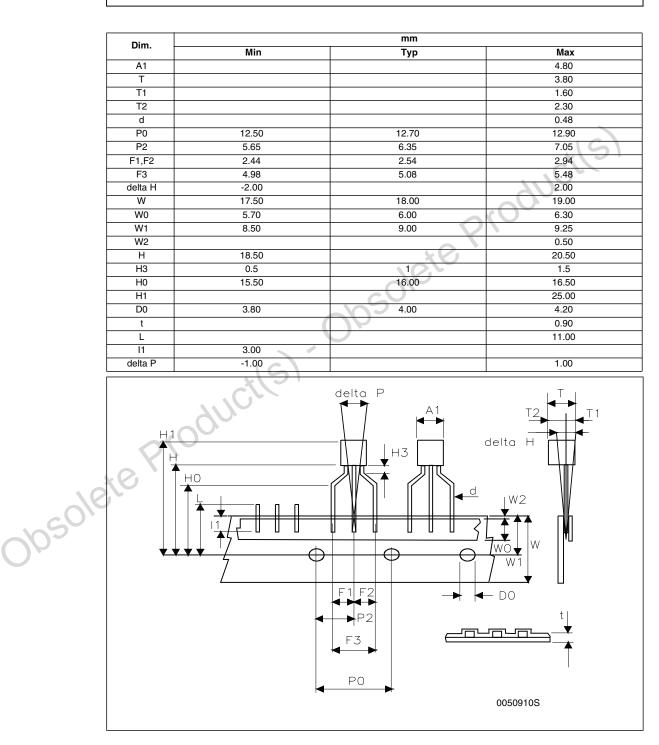
obsolete Product(s). Obsolete Product(s)

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| | TO-92 bulk s | hipment mechanical d | ata |
|------|--------------|----------------------|-------|
| DIM | | mm. | |
| DIM. | MIN. | ТҮР | MAX. |
| A | 4.32 | | 4.95 |
| b | 0.36 | | 0.51 |
| D | 4.45 | | 4.95 |
| E | 3.30 | | 3.94 |
| е | 2.41 | | 2.67 |
| e1 | 1.14 | | 1.40 |
| L | 12.70 | 2 | 15.49 |
| R | 2.16 | 10 | 2.41 |
| S1 | 0.92 | ler | 1.52 |
| W | 0.41 | bS | 0.56 |
| V | | 5° | |







TO-92 ammopack shipment (suffix"-AP") mechanical data



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4 Revision history

| Table 5. Document revision hist | orv |
|---------------------------------|-----|
|---------------------------------|-----|

| Date |
|-------------|
| 01-Apr-2009 |
| 21-Apr-2010 |
| 06-Jul-2010 |
| 06-Jul-2010 |



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